

Features

- Small body outline dimensions
- Protects one I/O or power line
- Low clamping voltage
- Working voltage: 15V
- Low leakage current

Mechanical Characteristics

- DFN1006-2L package
- Marking: Marking Code
- Packaging: Tape and Reel per EIA 481
- RoHS Compliant & HF

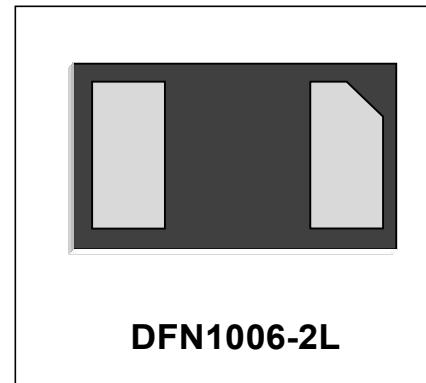
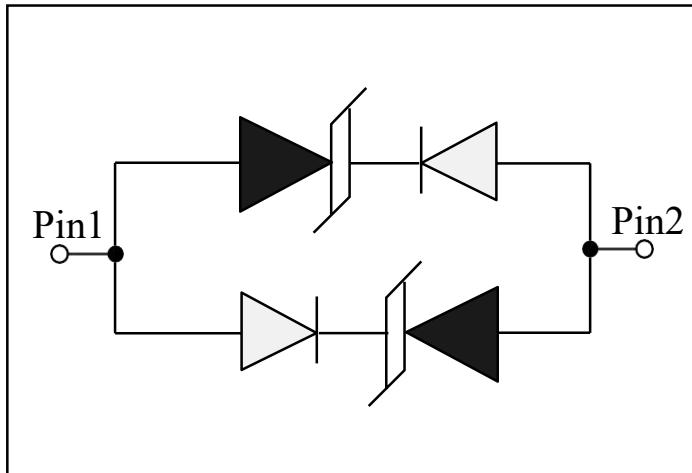
Applications

- Laptop computers
- Cellular phones
- Digital cameras
- Personal digital assistants (PDAs)

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 200A (8/20 μs)

Pin Configuration



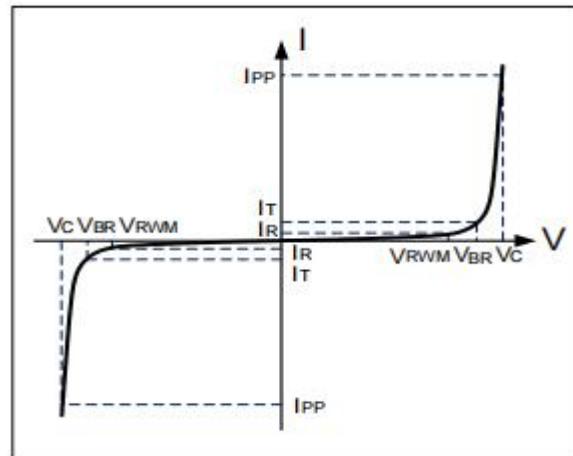
DFN1006-2L

Absolute Maximum Ratings(Ta=25°C)

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p=8/20\mu s$)	P_{PP}	62.5	W
Peak Pulse Current ($t_p=8/20\mu s$)	I_{PP}	2.5	A
Operating Temperature	T_J	-55 to + 125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Parameters (Ta=25°C)

Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ IPP
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ VRWM
V_{BR}	Breakdown Voltage @ IT
I_T	Test Current



Electrical Characteristics

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				15	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	16.5			V
Reverse Leakage Current	I_R	$V_{RWM}=15\text{V}$			200	nA
Clamping Voltage	V_c	$I_{PP}=2.5\text{A}, t_p=8/20\mu\text{s}$		23	25	V
ESD Clamping Voltage ¹	V_c	$I_{PP} = 4\text{A}$ $t_p = 0.2/100\text{ns}$		23.3		V
ESD Clamping Voltage ¹	V_c	$I_{PP} = 16\text{A}$ $t_p = 0.2/100\text{ns}$		37.8		V
Dynamic Resistance ^{1,2}	R_{DYN}	$TLP=0.2/100\text{ns}$		1.3		Ω
Junction Capacitance	C_j	$V_R = 0\text{V}, f = 1\text{MHz}$		0.7	1.2	pF

Note: 1、TLP Setting: $t_p=100\text{ns}, t_r=0.2\text{ns}, I_{TLP}$ and V_{TLP} sample window: $t_1=70\text{ns}$ to $t_2=90\text{ns}$.

2、Dynamic resistance calculated from $I_{PP}=4\text{A}$ to $I_{PP}=16\text{A}$ using “Best Fit”

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

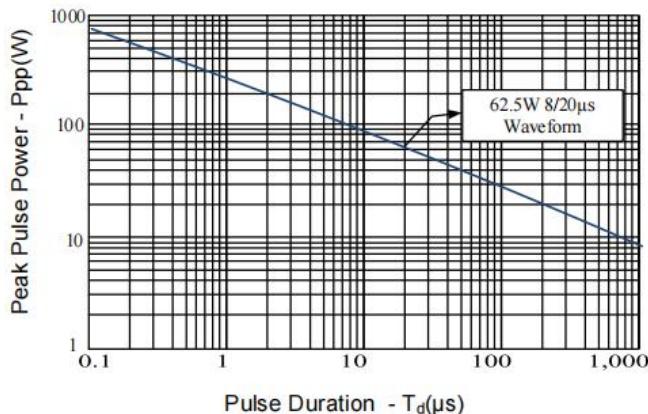


Figure 2: Power Derating Curve

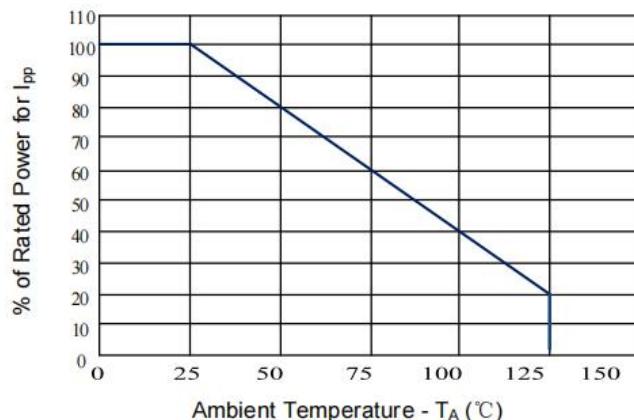


Figure 3: Clamping Voltage vs. Peak Pulse Current

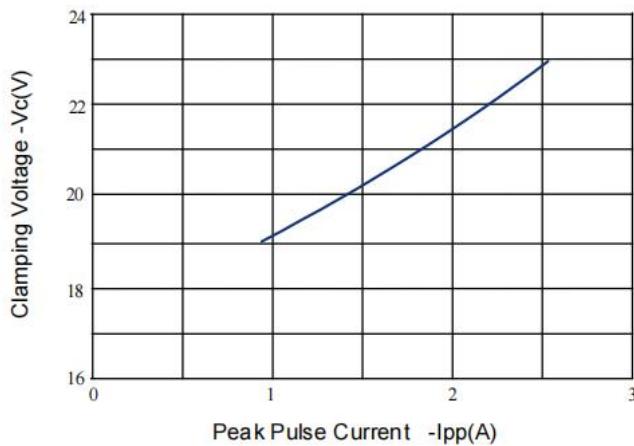


Figure 4: Normalized Junction Capacitance

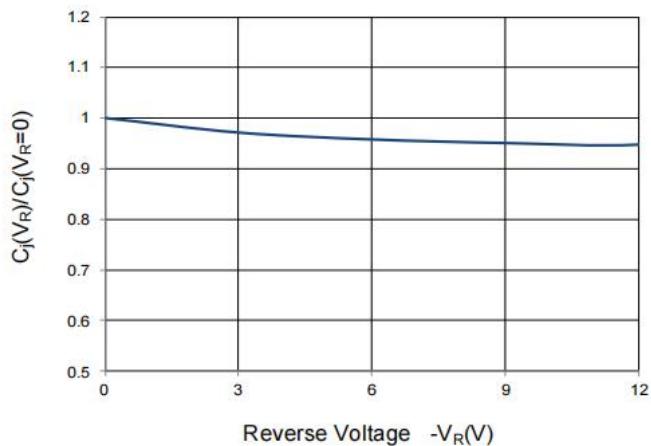


Figure 5: TLP Positive I-V Curve

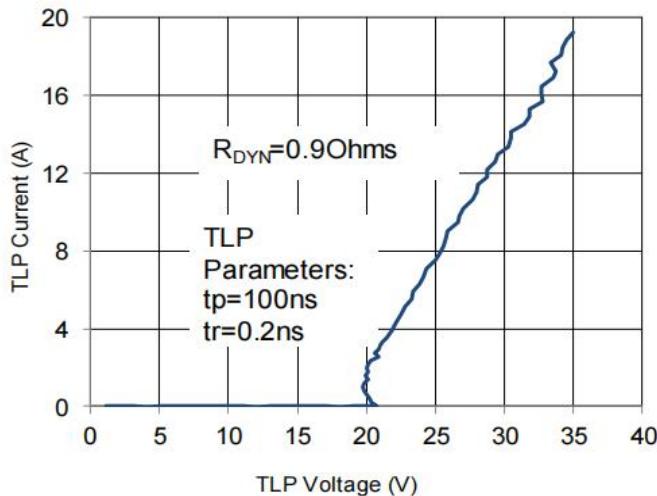
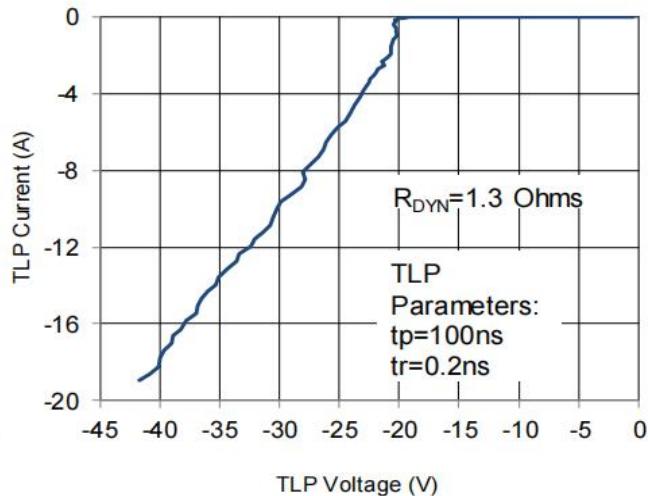


Figure 6: TLP Negative I-V Curve



Marking Codes

Part Number	Marking Code
CTSY15V0P1B2ZP	 QT=Specific Device Code X=Month Code

Package Information

Qty: 10k/Reel

Outline Drawing –DFN1006-2L

PACKAGE OUTLINE			
SYMBOL	MILLIMETERS		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	0	0.02	0.05
b	0.45	0.50	0.55
C	0.12	0.15	0.18
D	0.95	1.00	1.05
e	0.65BSC		
E	0.55	0.60	0.65
L	0.20	0.25	0.30
L1	0.05REF		
h	0.07	0.12	0.17

Land Pattern

